

isc N-Channel MOSFET Transistor

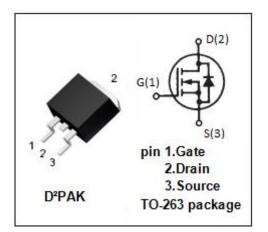
STB7ANM60N

• FEATURES

- With TO-263(D²PAK) packaging
- · High speed switching
- · Low gate input resistance
- · Standard level gate drive
- · Easy to use
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation



- Power supply
- Switching applications

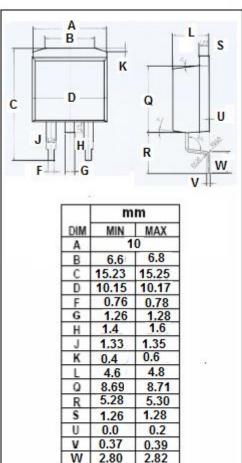


ABSOLUTE MAXIMUM RATINGS(T_a=25°C)

SYMBOL	PARAMETER	VALUE	UNIT	
V _{DSS}	Drain-Source Voltage	600	V	
V _{GSS}	Gate-Source Voltage	±25	V	
I _D	Drain Current-Continuous;@Tc=25℃	5	Α	
I _{DM}	Drain Current-Single Pulsed	20	Α	
P_D	Total Dissipation	45	W	
Tj	Operating Junction Temperature	150	$^{\circ}$	
T _{stg}	Storage Temperature	-55~150	$^{\circ}$	

• THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	MAX	UNIT
Rth(ch-c)	Channel-to-case thermal resistance	2.78	°C/W



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ELECTRICAL CHARACTERISTICS

Tc=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP	MAX	UNIT
BV _{DSS}	Drain-Source Breakdown Voltage	V _{GS} =0V; I _D = 1mA	600			V
V _{GS(th)}	Gate Threshold Voltage	V _{DS} =V _{GS} ; I _D =0.25mA	2		4	V
R _{DS(on)}	Drain-Source On-Resistance	V _{GS} = 10V; I _D = 2.5A			900	mΩ
I _{GSS}	Gate-Source Leakage Current	V _{GS} =±20V;V _{DS} = 0V			±0.1	μА
I _{DSS}	Drain-Source Leakage Current	V _{DS} = 600V; V _{GS} = 0V			1	μА
V _{SDF}	Diode forward voltage	I _{SD} = 5A, V _{GS} = 0 V			1.3	V



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